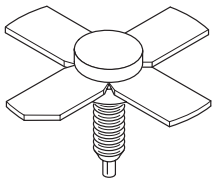
The RF Line
NPN Silicon RF Power Transistor

Designed for 12.5 Volt UHF large–signal amplifier applications in industrial and commercial FM equipment operating to 512 MHz.

- Specified 12.5 Volt, 512 MHz Characteristics
  Output Power = 10 W
  Gain = 8.0 dB (Typ)
  Efficiency = 65% (Typ)
- Gold Metallized, Emitter Ballasted for Long Life and Reliability
- Capable of 20:1 VSWR Load Mismatch at 16 V Supply Voltage
- Circuit board photomaster available upon request by contacting RF Tactical Marketing in Phoenix, AZ.

MRF653

10 W, 512 MHz
RF POWER
TRANSISTOR
NPN SILICON



CASE 244–04, STYLE 1

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V_{CEO}	16.5	Vdc
Collector–Base Voltage	V_{CBO}	38	Vdc
Emitter–Base Voltage	V_{EBO}	4.0	Vdc
Collector Current — Continuous	I_C	2.75	Adc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D	44 0.25	Watts W/°C
Storage Temperature Range	T_{stg}	–65 to +150	°C
Operating Junction Temperature	T_J	200	°C

THERMAL CHARACTERISTICS

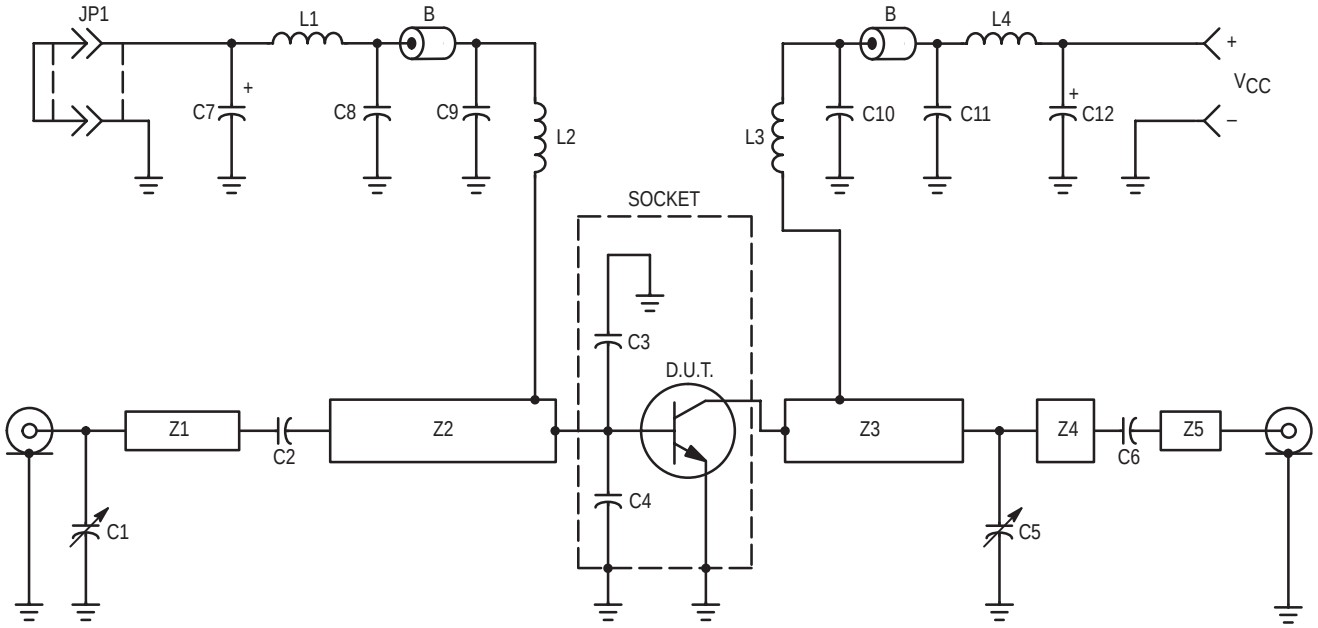
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	4.0	°C/W

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage (I_C = 20 mAdc, I_B = 0)	$V_{(BR)CEO}$	16.5	—	—	Vdc
Collector–Emitter Breakdown Voltage (I_C = 20 mAdc, V_{BE} = 0)	$V_{(BR)CES}$	38	—	—	Vdc
Emitter–Base Breakdown Voltage (I_E = 5.0 mAdc, I_C = 0)	$V_{(BR)EBO}$	4.0	—	—	Vdc
Collector Cutoff Current (V_{CE} = 15 Vdc, V_{BE} = 0)	I_{CES}	—	—	5.0	mAdc
ON CHARACTERISTICS					
DC Current Gain (I_C = 1.0 Adc, V_{CE} = 5.0 Vdc)	h_{FE}	20	—	120	—
DYNAMIC CHARACTERISTICS					
Output Capacitance (V_{CB} = 12.5 Vdc, I_E = 0, f = 1.0 MHz)	C_{ob}	—	22	28	pF
FUNCTIONAL TESTS					
Common–Emitter Amplifier Power Gain (V_{CC} = 12.5 Vdc, P_{out} = 10 W, f = 512 MHz)	G_{pe}	7.0	8.0	—	dB
Collector Efficiency (V_{CC} = 12.5 Vdc, P_{out} = 10 W, f = 512 MHz)	η_c	55	65	—	%
Load Mismatch Stress (V_{CC} = 16 Vdc, f = 512 MHz, P_{in} (1) = 2.6 W, VSWR = 20:1, All Phase Angles)	ψ	No Degradation in Output Power			

NOTE:
1. P_{in} = 2.0 dB over the typical input power required for 10 W output power @ 12.5 Vdc.

NOT RECOMMENDED FOR NEW DESIGN



C1, C5 — 1.0–20 pF, Johanson
C2, C6 — 330 pF, 100 Mil ATC
C3, C4 — 36 pF, Mini–Unelco
C7, C12 — 10 μF, 35 V, Tantalum
C8, C11 — 0.1 μF, Ceramic
C9, C10 — 91 pF, Mini–Unelco

L1, L4 — 4–1/2 Turns, #18 AWG, 0.16″ ID
L2, L3 — 2 Turns, #18 AWG, 0.16″ ID
B — Ferrite Bead, Ferroxcube 56–590–65–3B
Z1 — 51 x 630 mils
Z2 — 162 x 1300 mils
Z3 — 210 x 1350 mils
Z4 — 210 x 280 mils
Z5 — 51 x 300 mils
Board Material — 0.032″ epoxy glass G10, 1 oz., copper clad, double sided, ε_r = 5
JP1 — Jumper, #14 AWG w/Banana Plugs

Figure 1. Broadband Test Circuit Schematic

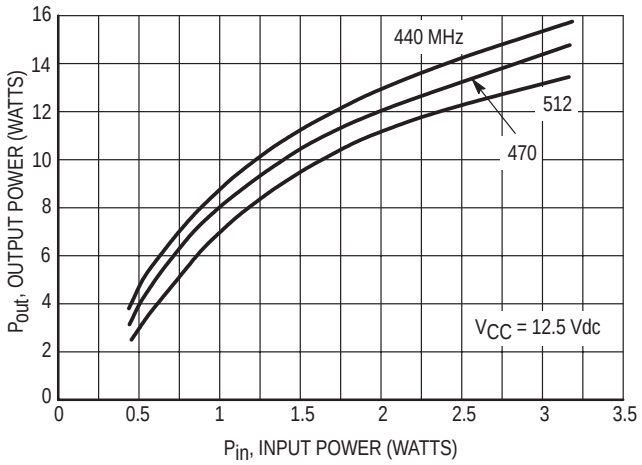


Figure 2. Output Power versus Input Power

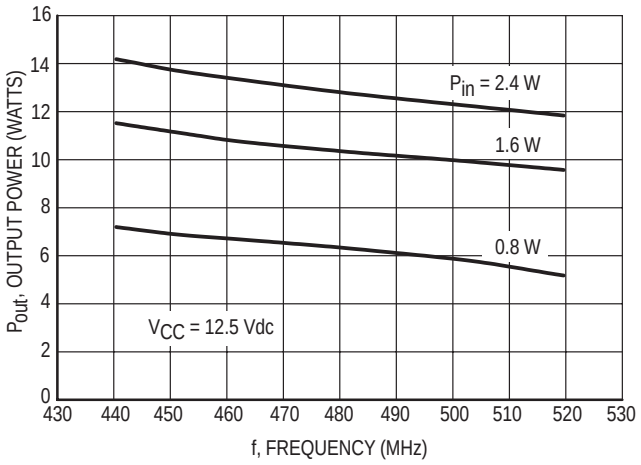


Figure 3. Output Power versus Frequency

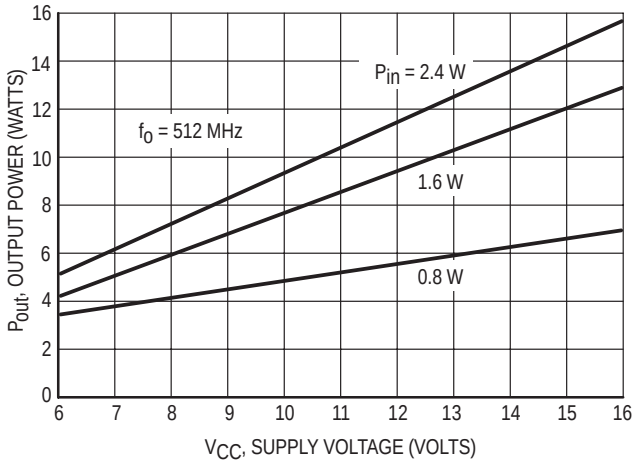


Figure 4. Output Power versus Supply Voltage

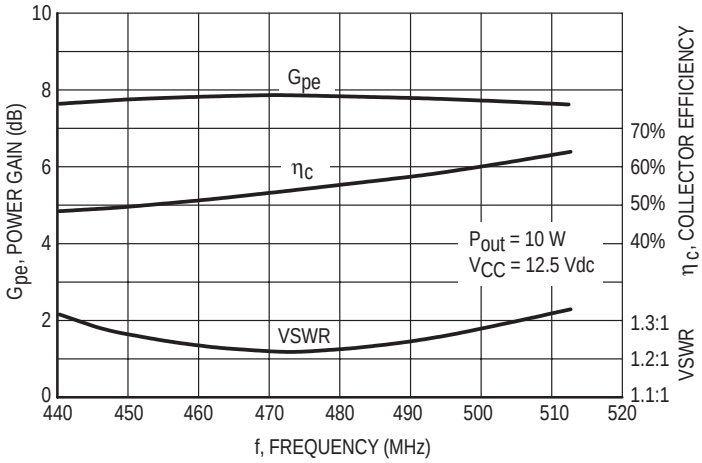


Figure 5. Typical Broadband Circuit Performance

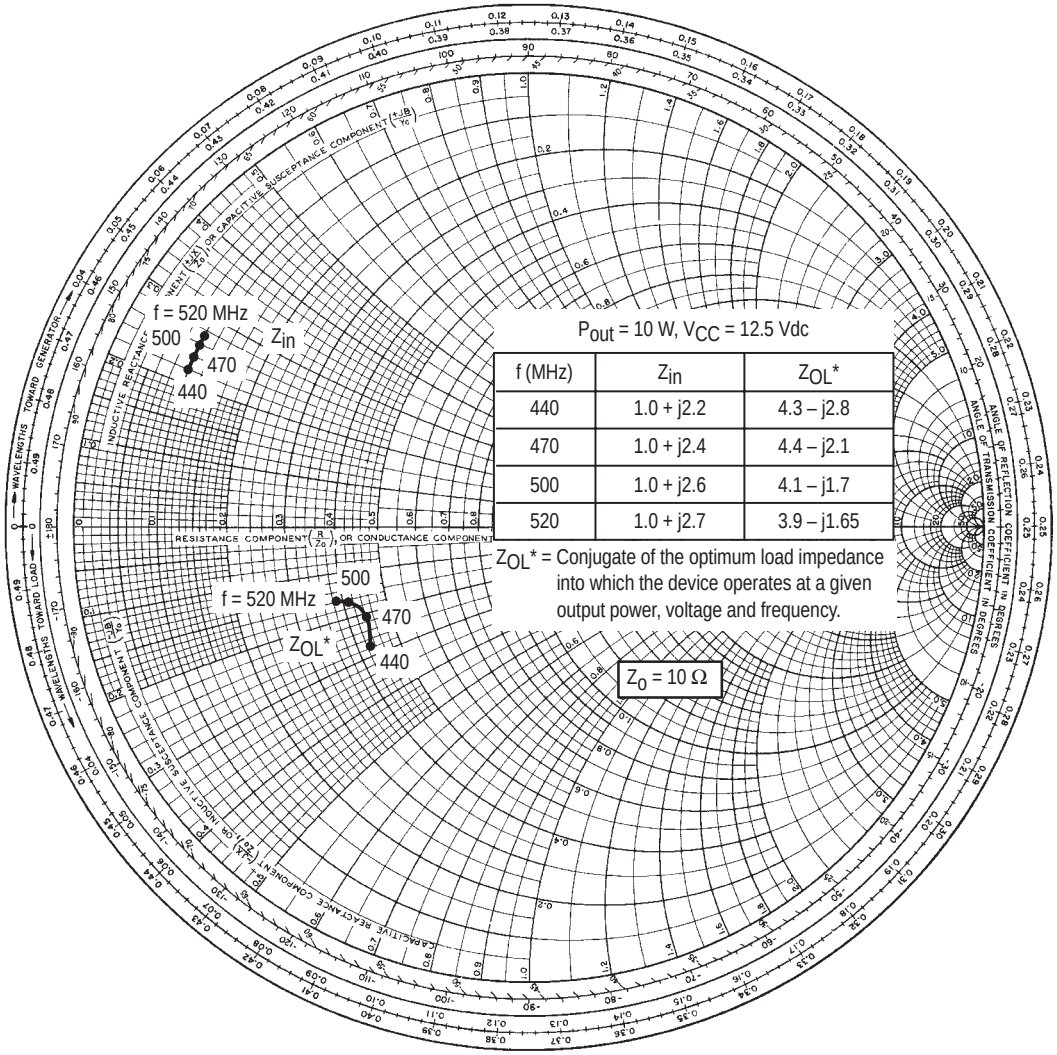
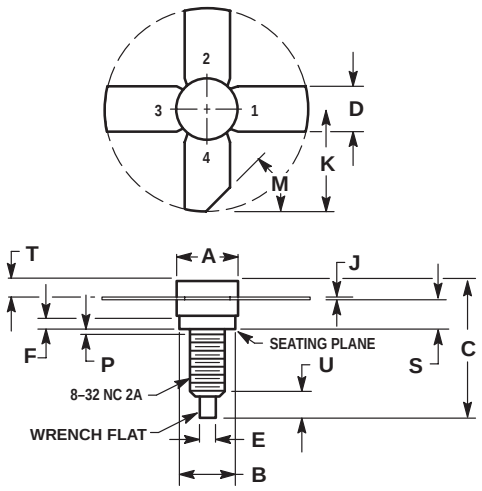


Figure 6. Series Equivalent Input and Output Impedance

PACKAGE DIMENSIONS



DIM	MILLIMETERS MIN	MILLIMETERS MAX	INCHES MIN	INCHES MAX
A	7.06	7.26	0.278	0.286
B	6.20	6.50	0.244	0.256
C	14.99	16.51	0.590	0.650
D	5.46	5.96	0.215	0.235
E	1.40	1.65	0.055	0.065
G	1.52	—	0.060	—
J	0.08	0.17	0.003	0.007
K	11.05	—	0.435	—
M	45° NOM		45° NOM	
P	—	1.27	—	0.050
S	3.00	3.25	0.118	0.128
T	1.40	1.77	0.055	0.070
U	2.92	3.68	0.115	0.145

STYLE 1:
PIN 1. EMITTER
2. BASE
3. EMITTER
4. COLLECTOR

CASE 244–04
ISSUE J

NOTES

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